

# KBU6005/RS601/KBU6A THRU KBU610/RS607/KBU6M

## SINGLE-PHASE SILICON BRIDGE RECTIFIER

VOLTAGE: 50-1000V

CURRENT: 6.0A

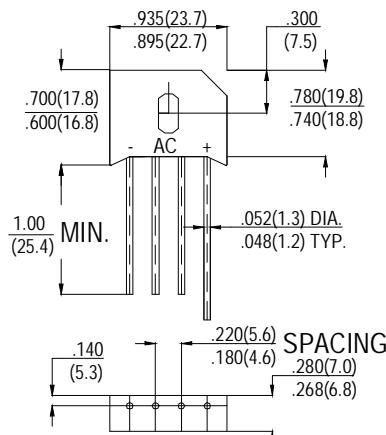
### FEATURES

- Low leakage
- Low forward voltage
- Surge overload ratings-250 Amperes
- Molded structure

### MECHANICAL DATA

- **Case:** Molded plastic
- **Epoxy:** UL 94V-0 rate flame retardant
- **Lead:** MIL-STD- 202E, Method 208 guaranteed
- **Polarity:** Symbols molded or marked on body
- **Mounting position:** Any
- **Weight:** 8.0 grams

### KBU



Dimensions in inches and (millimeters)

### MAXIMUM RATINGS AND ELECTRONICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

Single phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

	SYMBOL	KBU6005	KBU601	KBU602	KBU604	KBU606	KBU608	KBU610	units
		RS601	RS602	RS603	RS604	RS605	RS606	RS607	
		KBU6A	KBU6B	KBU6D	KBU6G	KBU6J	KBU6K	KBU6M	
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	50	100	200	400	600	800	1000	<b>V</b>
Maximum RMS Bridge Input Voltage	$V_{RMS}$	35	70	140	280	420	560	700	<b>V</b>
Maximum DC Blocking Voltage	$V_{DC}$	50	100	200	400	600	800	1000	<b>V</b>
Maximum Average Forward rectified Output Current at $T_c=75^\circ C$	$I_o$	6.0							<b>A</b>
Peak Forward Surge Current 8.3ms single half sine-wave superimposed on rated load (JEDEC method)	$I_{FSM}$	200							<b>A</b>
Maximum Forward Voltage Drop per element at 3.0A DC	$V_F$	1.0							<b>V</b>
Maximum DC Reverse Current at Rated DC Blocking Voltage per element @ $T_A=25^\circ C$	$I_R$	10						$\mu A$	
		500							
$I^2t$ Rating for Fusing ( $t < 8.3\text{ms}$ )	$I^2t$	127						$A^2S_{ec}$	
Typical Junction Capacitance (Note 1)	$C_J$	186						$pF$	
Typical Thermal Resistance (Note 2)	$R_{\theta JA}$	10						$^\circ C/W$	

Notes: 1. Measured at 1MHz and applied reverse voltage of 4.0 volts

2. Thermal Resistance from Junction to Ambient with units mounted on  $0.47 \times 0.47$ " (12x12mm) copper pads